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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





Features

- **Power Amplifier with High Power Added Efficient (PAE), P_{out} Typically 29 dBm**
- **Controlled Output Power**
- **Low-noise Preamplifier (NF Typically 1.7 dB)**
- **Few External Components**
- **PSSO16 Plastic Package with Down Set Paddle**

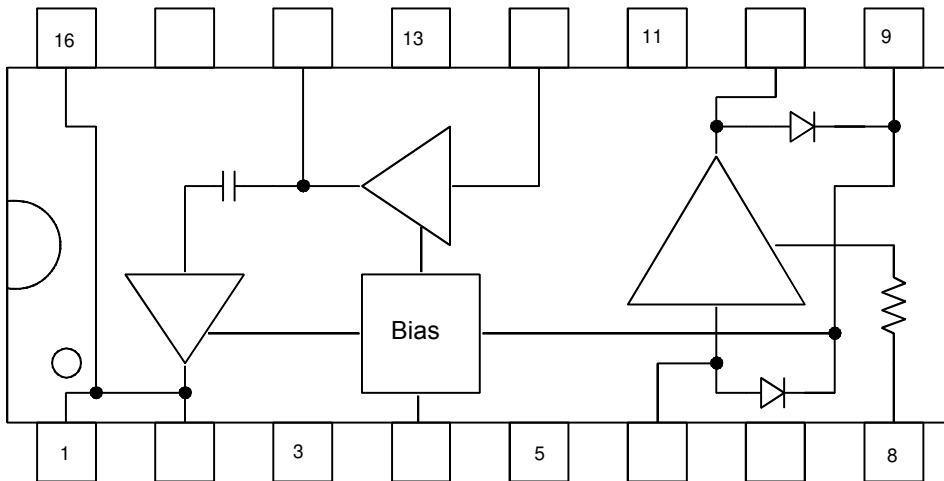
Description

The T0980 is a monolithic IC manufactured with Atmel's advanced SiGe technology. The IC performs a transmit and receive front-end dedicated for a frequency range of 400 MHz to 500 MHz. It consists of a Low-Noise Amplifier (LNA) and a Power Amplifier (PA) with good Power Efficiency (PAE).

Electrostatic sensitive device.
Observe precautions for handling.



Figure 1. Block Diagram



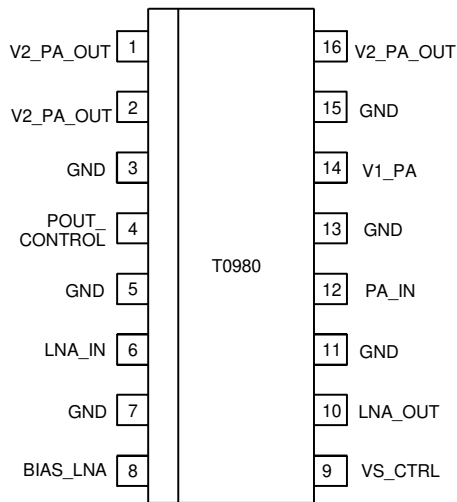
SiGe Transmit/ Receive Front- end IC

T0980



Pin Configuration

Figure 2. Pinning PSSOP16



Pin Description

Pin	Symbol	Function
1	V2_PA_OUT	Inductor to power supply and matching network for power amplifier output
2	V2_PA_OUT	Inductor to power supply and matching network for power amplifier output
3	GND	Ground
4	POUT_CONTROL	Power amplifier control input
5	GND	Ground
6	LNA_IN	Low-noise amplifier input
7	GND	Ground
8	BIAS_LNA	Resistor to V_S sets the LNA current
9	VS_CTRL	Supply voltage for control of power amplifier
10	LNA_OUT	Low-noise amplifier output and supply voltage
11	GND	Ground
12	PA_IN	Power amplifier input
13	GND	Ground
14	V1_PA	Supply voltage for power amplifier
15	GND	Ground
16	V2_PA_OUT	Matching network for power amplifier output

Absolute Maximum Ratings

All voltages are referred to GND

Parameters	Symbol	Min.	Max.	Unit
Supply voltage PA, TX Pins 1, 2, 9 and 14	V_{S_PA}		4.8	V
Supply voltage LNA, RX Pin 10	V_{S_LNA}		2.8	V
Junction temperature	T_{jmax}		150	°C
Storage temperature	T_{Stg}	-55	+125	°C
Electrostatic handling HMB; Pins 1, 2, 6, 10, 12 and 16	V_{ESD}		200	V
Electrostatic handling HMB; Pins 3, 4, 5, 7, 8, 9, 11, 13, 14 and 15	V_{ESD}		2000	V

Operating Range

All voltages are referred to GND. The following table represents the sum of all supply currents.

Parameters	Test Conditions/Pins	Symbol	Min.	Typ.	Max.	Unit
Supply voltage PA	TX, Pins 1, 2, 9 and 14	V_{S_PA}		3.6	4.5	V
Supply voltage LNA	RX, Pin 10	V_{S_LNA}		2.5	2.6	V
Supply current PA	TX, Pins 1, 2, 9 and 14	I_{S_PA}		400		mA
Supply current LNA	Pins 10 and 8	I_{S_LNA}		2.5		mA
Ambient temperature		T_{amb}	-25	25	60	°C

Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient	R_{thJA}	25	K/W

Electrical Characteristics

Test conditions (unless otherwise specified) : $V_{S_PA} = 3.6\text{ V}$, $T_{amb} = 25^\circ\text{C}$.

Parameters	Test Conditions/Pins	Symbol	Min.	Typ.	Max.	Unit
Power Amplifier ⁽¹⁾						
Supply voltage	TX, Pins 1, 2, 9 and 14	V_{S_PA}		3.6		V
Supply current	TX, Pins 1, 2, 9 and 14	I_{S_PA}		400		mA
Frequency range	TX	f	400		500	MHz
Power gain	TX	Gp		33		dB
Control voltage	TX, output power (maximum), Pin 4			2.5		V
	TX, output power (minimum), Pin 4			0.7		V
Control current	Pin 4		0		400	μA
Shut down mode	Control voltage $\leq 0.1\text{ V}$, Pins 1, 2, 9 and 14	I_{S_PA}		10		μA
Power added efficiency	TX at 450 MHz	PAE	50			%
Saturated output power	TX, input power 3 dBm	Psat		29		dBm
Harmonics	TX, input power 3 dBm	2 fo		-20		dBc
	TX, input power 3 dBm	3 fo		-20		dBc
Low-noise Amplifier						
Supply voltage	RX, Pins 8 and 10	V_{S_LNA}		2.5		V
Supply current	RX at R1 = 5.6 k Ω , Pins 8 and 10	I_{S_LNA}		2.5		mA
Frequency range	RX	f	400		500	MHz
Power gain	RX at R1 = 5.6 k Ω , Is = 2.5 mA	Gp		19		dB
Noise figure	RX at R1 = 5.6 k Ω , Is = 2.5 mA	NF		1.7	2.5	dB
Isolation	RX at R1 = 5.6 k Ω , Is = 2.5 mA	ISO		20		dB
3rd-order input interception point	RX at R1 = 5.6 k Ω , Is = 2.5 mA	IIP3		-10		dBm

Note: 1. Power amplifier should be unconditional stable, maximum duty cycle 100%, true cw-operation, maximum load mismatch 10:1 for 5 s at 3.6 V

Typical Characteristics

Figure 3. Power Sweep

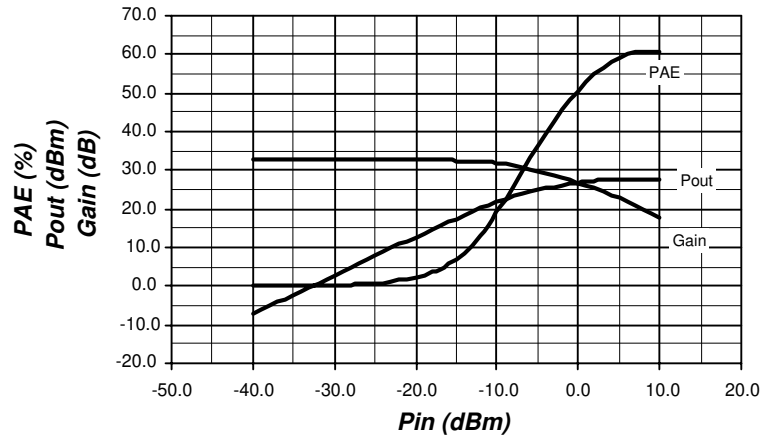


Figure 4. Ramp Sweep

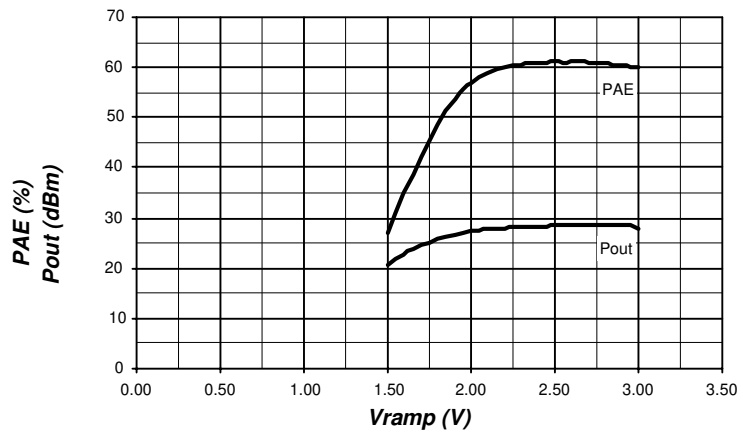


Figure 5. V_{CC} Sweep

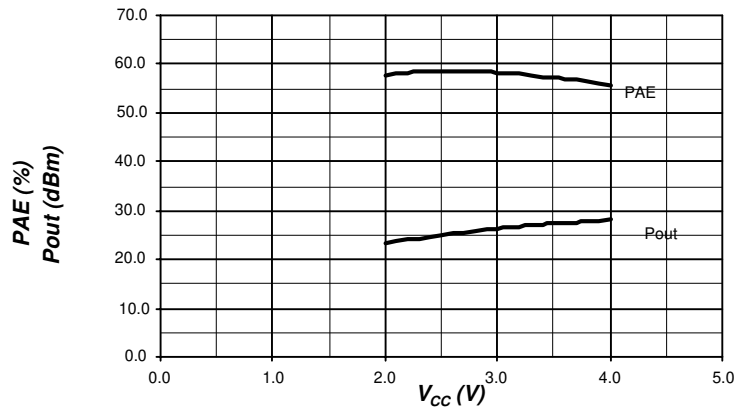
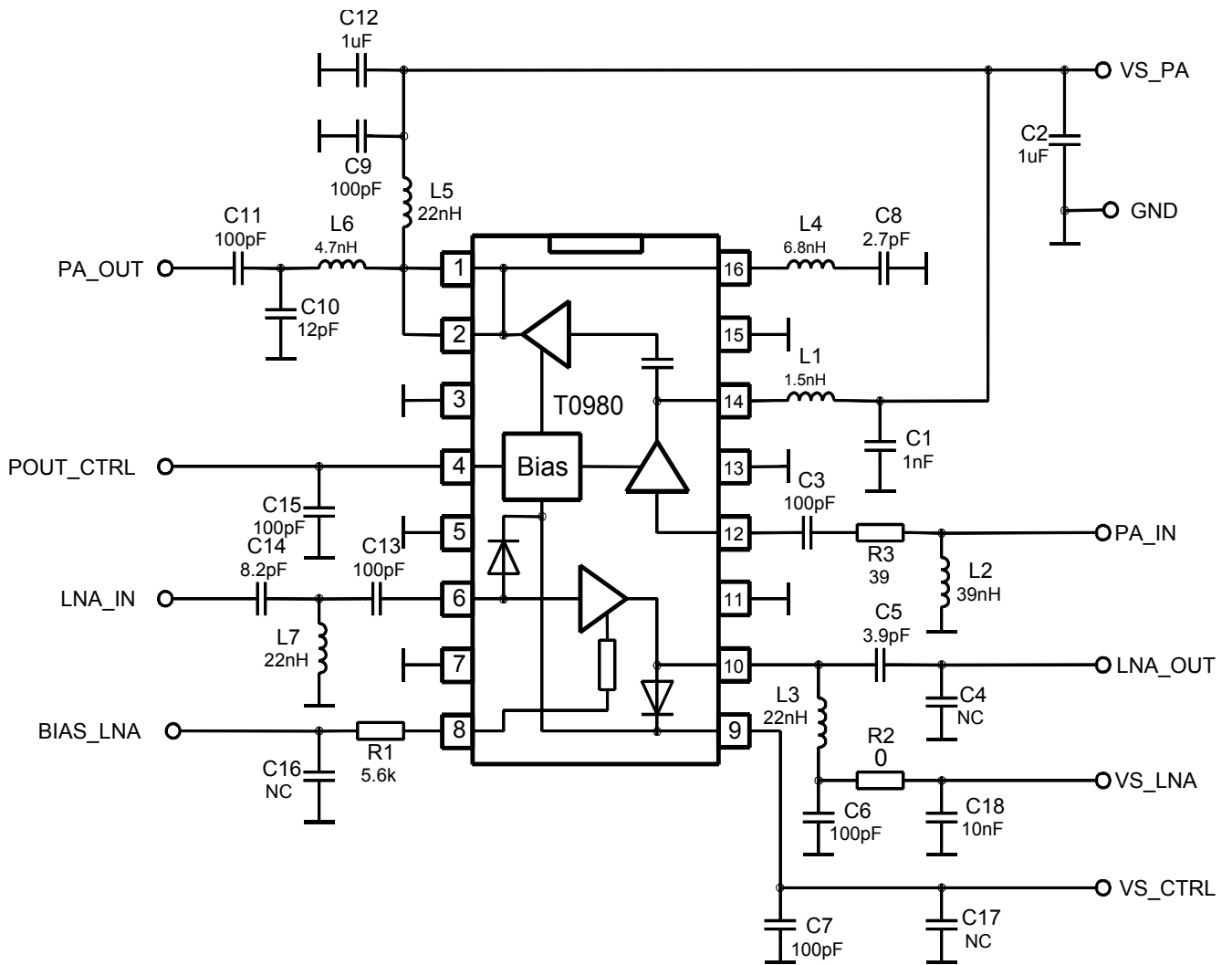


Figure 6. Typical Application Circuit (460 MHz)



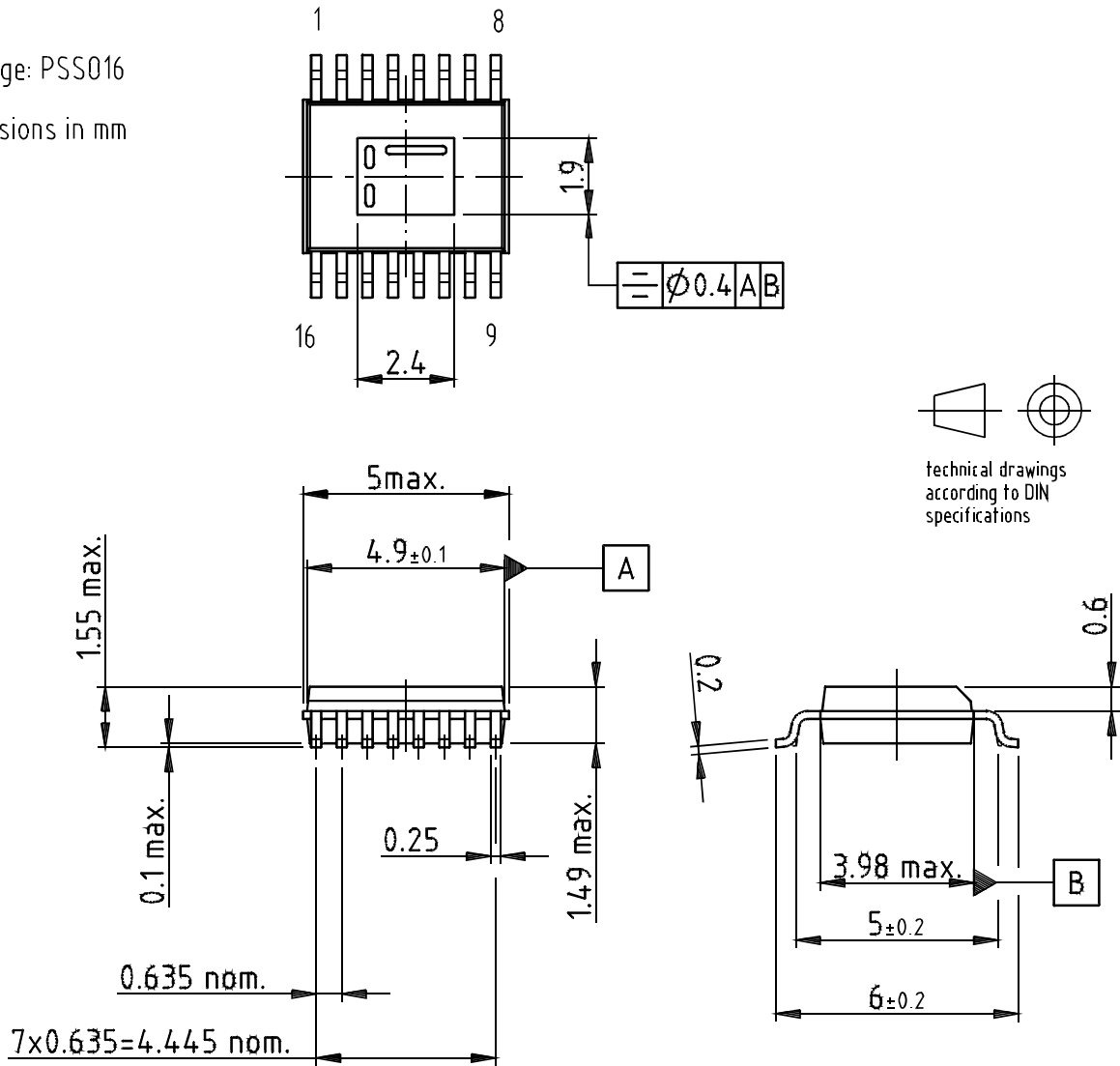
Ordering Information

Extended Type Number	Package	Remarks
T0980-TJS	PSSO16	Tube
T0980-TJQ	PSSO16	Taped and reeled

Package Information

Package: PSSO16

Dimensions in mm



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Atmel Headquarters

Corporate Headquarters

2325 Orchard Parkway
San Jose, CA 95131
TEL 1(408) 441-0311
FAX 1(408) 487-2600

Europe

Atmel Sarl
Route des Arsenaux 41
Case Postale 80
CH-1705 Fribourg
Switzerland
TEL (41) 26-426-5555
FAX (41) 26-426-5500

Asia

Room 1219
Chinachem Golden Plaza
77 Mody Road Tsimhatsui
East Kowloon
Hong Kong
TEL (852) 2721-9778
FAX (852) 2722-1369

Japan

9F, Tonetsu Shinkawa Bldg.
1-24-8 Shinkawa
Chuo-ku, Tokyo 104-0033
Japan
TEL (81) 3-3523-3551
FAX (81) 3-3523-7581

Atmel Operations

Memory

2325 Orchard Parkway
San Jose, CA 95131
TEL 1(408) 441-0311
FAX 1(408) 436-4314

Microcontrollers

2325 Orchard Parkway
San Jose, CA 95131
TEL 1(408) 441-0311
FAX 1(408) 436-4314

La Chantrerie
BP 70602
44306 Nantes Cedex 3, France
TEL (33) 2-40-18-18-18
FAX (33) 2-40-18-19-60

ASIC/ASSP/Smart Cards

Zone Industrielle
13106 Rousset Cedex, France
TEL (33) 4-42-53-60-00
FAX (33) 4-42-53-60-01

1150 East Cheyenne Mtn. Blvd.
Colorado Springs, CO 80906
TEL 1(719) 576-3300
FAX 1(719) 540-1759

Scottish Enterprise Technology Park
Maxwell Building
East Kilbride G75 0QR, Scotland
TEL (44) 1355-803-000
FAX (44) 1355-242-743

RF/Automotive

Theresienstrasse 2
Postfach 3535
74025 Heilbronn, Germany
TEL (49) 71-31-67-0
FAX (49) 71-31-67-2340

1150 East Cheyenne Mtn. Blvd.
Colorado Springs, CO 80906
TEL 1(719) 576-3300
FAX 1(719) 540-1759

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Avenue de Rochepleine
BP 123
38521 Saint-Egreve Cedex, France
TEL (33) 4-76-58-30-00
FAX (33) 4-76-58-34-80

e-mail

literature@atmel.com

Web Site

<http://www.atmel.com>

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